



#8A
Amott
SDavis
3/4/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: HIROYAMA, Ryouji et al.

Group Art Unit: 2815

Serial No.: 09/669,448 ✓

Examiner: Matthew C. Landau

Filed: September 25, 2000 ✓

P.T.O. Confirmation No.: 2968

For: SEMICONDUCTOR LASER DEVICE AND METHOD OF MANUFACTURING THE SAME

AMENDMENT UNDER 37 CFR §1.111

Commissioner for Patents
Washington, D.C. 20231

February 24, 2003

Sir:

In response to the Office Action dated September 12, 2002, extended to March 12, 2003 by a 3 month Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Cancel claim 8 without prejudice or disclaimer.

Amend claims 1, 2 and 4-7 as indicated below:

1. (Amended) A semiconductor laser device comprising:

a substrate;

a first conductivity type cladding layer;

an emission layer;

a second conductivity type cladding layer containing Al as a group III element and formed with a ridge portion;

RECEIVED
TECHNOLOGY CENTER
FEB 28 2003
2000